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Radiation Hardened Quad Differential Line Driver

intercil

The Intersil HS-26CT31RH is a quad differential line driver designed for digital data transmission over balanced lines and meets the requirements of EIA standard RS-422. Radiation hardened CMOS processing assures low power consumption, high speed, and reliable operation in the most severe radiation environments.

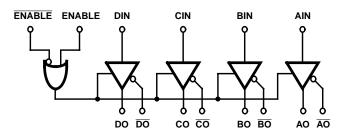
The HS-26CT31RH accepts TTL signal levels and converts them to RS-422 compatible outputs. This circuit uses special outputs that enable the drivers to power down without loading down the bus. Enable and disable pins allow several devices to be connected to the same data source and addressed independently.

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed here must be used when ordering.

Detailed Electrical Specifications for these devices are contained in SMD 5962-95632. A "hot-link" is provided on our homepage for downloading.

http://www.intersil.com/spacedefense/space.htm

Logic Diagram



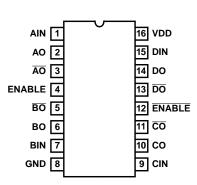
Ordering Information

ORDERING NUMBER	INTERNAL MKT. NUMBER	TEMP. RANGE (^o C)
5962F9563201QEC	HS1-26CT31RH-8	-55 to 125
5962F9563201QXC	HS9-26CT31RH-8	-55 to 125
5962F9563201V9A	HS0-26CT31RH-Q	25
5962F9563201VEC	HS1-26CT31RH-Q	-55 to 125
5962F9563201VXC	HS9-26CT31RH-Q	-55 to 125
HS1-26CT31RH/PROTO	HS1-26CT31RH/PROTO	-55 to 125
HS9-26CT31RH/PROTO	HS9-26CT31RH/PROTO	-55 to 125

Features

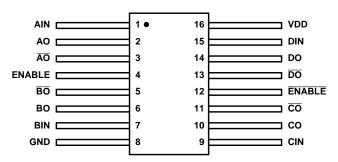
- Electronically Screened to SMD #5962-95632
- QML Qualified Per MIL-PRF-38535 Requirements
- 1.2 Micron Radiation Hardened CMOS
- Total Dose Up to 300kRAD(Si)
- Latchup Free
- EIA RS-422 Compatible Outputs (Except for IOS)
- TTL Compatible Inputs
- High Impedance Outputs when Disabled or Powered Down
- Low Power Dissipation 2.75mW Standby (Max)
- Single 5V Supply
- Low Output Impedance 10Ω or Less
- Full -55°C to +125°C Military Temperature Range

Pinouts



HS1-26CT31RH (SBDIP) CD1P2-T16 TOP VIEW

HS9-26CT31RH (FLATPACK) CDFP4-F16 TOP VIEW



CAUTION: These devices are sensitive to electrostatic discharge; follow proper IC Handling Procedures. http://www.intersil.com or 407-727-9207 | Copyright © Intersil Corporation 1999

Die Characteristics

DIE DIMENSIONS:

96.5 mils x 195 mils x 21 mils (2450 x 4950)

INTERFACE MATERIALS:

Glassivation:

Type: PSG (Phosphorus Silicon Glass) Thickness: 10kÅ ±1kÅ

Metallization:

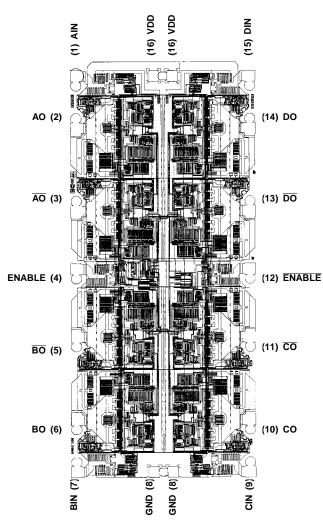
M1: Mo/TiW Thickness: 5800Å M2: Al/Si/Cu (Top) Thickness: 10kÅ ±1kÅ

Metallization Mask Layout

Substrate: AVLSI1RA Backside Finish: Silicon ASSEMBLY RELATED INFORMATION: Substrate Potential (Powered Up): V_{DD} ADDITIONAL INFORMATION: Worst Case Current Density: <2.0 x 10⁵A/cm²

Bond Pad Size: 110μm x 100μm

HS26CT31RH



All Intersil semiconductor products are manufactured, assembled and tested under ISO9000 quality systems certification.

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